

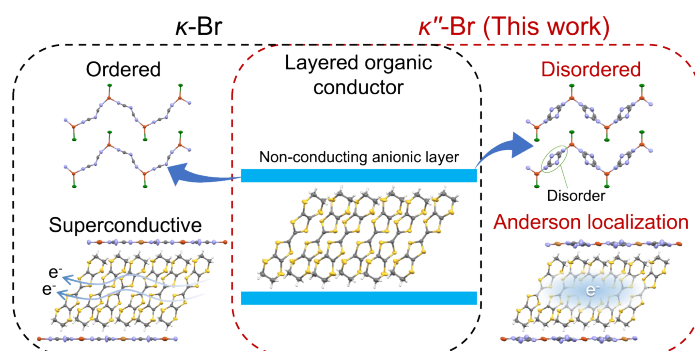
## Optical and low-temperature transport properties of an organic conductor with disordered anion structure $\kappa''\text{-(ET)}_2\text{Cu[N(CN)}_2\text{]Br}$

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**Keywords:** BEDT-TTF; Organic conductor; Disorder; Conductivity; Optical properties; Electron localization

The organic conductors  $\kappa\text{-(ET)}_2\text{X}$  have been known as highly correlated electronic systems where a superconducting phase is located in the vicinity of a Mott-insulating phase.<sup>1</sup> Recently, the effect of structural disorder in  $\kappa\text{-(ET)}_2\text{X}$  has attracted much attention. For example, X-ray irradiation induces lattice defects, leading to a disorder-induced metal–insulator transition in the superconducting  $\kappa\text{-(ET)}_2\text{Cu[N(CN)}_2\text{]Br}$  ( **$\kappa\text{-Br}$** )<sup>2</sup> and the suppression of long-range magnetic order in the Mott-insulating  $\kappa\text{-(ET)}_2\text{Cu[N(CN)}_2\text{]Cl}$  ( **$\kappa\text{-Cl}$** ).<sup>3</sup> However, the destructive X-ray irradiation may also induce secondary effects such as carrier doping due to ionization and local modulation of Coulomb interactions.<sup>4</sup> To elucidate the intrinsic effect of a random potential, a nondestructive method such as chemically-introduced/controlled disorder in the anion layer while keeping the ordered conducting ET layer is desirable.

Recently, we succeeded in synthesizing  $\kappa''\text{-(ET)}_2\text{Cu[N(CN)}_2\text{]Br}$  ( **$\kappa''\text{-Br}$** ), which is the first polymorph of  **$\kappa\text{-Br}$** , having very similar conducting ET layers but disordered insulating anion layers in contrast to those of  **$\kappa\text{-Br}$** . It was found that the  **$\kappa''\text{-Br}$**  is neither a conventional superconductor nor a Mott insulator, but the detailed electronic states remained unclear. In this study, we investigated the ground state of  **$\kappa''\text{-Br}$**  from the results of reflectance spectroscopy, Raman scattering spectroscopy, and low-temperature resistivity behavior obtained by using a high-quality single crystal of  **$\kappa''\text{-Br}$**  which is free from crystal twinning or magnetic impurities. Our results suggest the occurrence of Anderson localization in  **$\kappa''\text{-Br}$**  due to disordered anion layers.



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